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Application Number	10/468,183
Filing Date	April 28, 2004
First Named Inventor	Markus-Christian Amann
Art Unit	2826 2823
Examiner Name	Winston On Harvey Khien D.
Attorney Docket Number	411883

(Use as many sheets as necessary)

Sheet	1	of	2
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[illegible][illegible]

Examiner Signature	/Kiem Nguyen/	Date Considered	10/29/2008
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Transalation is attached.

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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet 2 of 2

Complete if Known

Application Number	10/468,183
Filing Date	April 28, 2004
First Named Inventor	Markus-Christian Amann
Art Unit	2828
Examiner Name	Minsun Oh Harvey
Attorney Docket Number	411883

NON PATENT LITERATURE DOCUMENTS

Examiner Initials *	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/KN/		ORTSIEFER, M. et al.: "Low-Threshold Index-Guided 1.5 Mum Long-Wavelength Vertical-Cavity Surface-Emitting Laser With High Efficiency", Applied Physics Letters, American Institute of Physics, New York, US, pg. 2179-2181, April 17, 2000	
		NAKAGAWA, S. et al.: "88° Continuous-Wave Operation Of Apertured, Intracavity Contacted, 1.55 Mum Vertical-Cavity Surface-Emitting Lasers" Applied Physics Letters, American Institute of Physics, New York, US, pg 1337-1339, March 5, 2001	
		ORTSIEFER, M. et al.: "Submilliamp Long-Wavelength InP-Based Vertical-Cavity Surface-Emitting Laser With Stable Linear Polarisation" Electronics Letters, IEE Stevenage, pg. 1124-1126, June 22, 2000	
		ORTSIEFER, M. et al.: "90°C Continuous-Wave Operation Of 1.83-Mum Vertical-Cavity Surface-Emitting Lasers" IEEE Photonics Technology Letters, IEE Inc., New York, US, pgs 1435-1437, November 2000	
		SCHRAUD, G. et al.: "Substrateless Singlemode Vertical Cavity Surface-Emitting GaAs/GaAlAs Laser Diode" Electronics Letters, IEE Stevenage, GB, pgs 238-239, February 3, 1994	
		LIAU, Z.L., et al.: "A Novel Technique For Gainasp/Inp Buried Heterostructure Laser Fabrication" Applied Physics Letters, American Institute of Physics, New York, US, pg 568-570, April 1, 1982	
		International Preliminary Examination Report for PCT/EP2003/012433	

Examiner Signature	/Kiem Nguyen/	Date Considered	10/29/2008
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